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Octal inverting buffer (3-State)   74ABT240

FEATURES

- Octal bus interface
- 3-State buffers
- Output capability: +64mA/–32mA
- Latch-up protection exceeds 500mA per Jedec Std 17
- ESD protection exceeds 2000 V per MIL STD 883 Method 3015 and 200 V per Machine Model
- Power-up 3-State
- Live insertion/extraction permitted

DESCRIPTION

The 74ABT240 high-performance BiCMOS device combines low static and dynamic power dissipation with high speed and high output drive.

The 74ABT240 device is an octal inverting buffer that is ideal for driving bus lines. The device features two Output Enables ($1\overline{OE}$, $2\overline{OE}$), each controlling four of the 3-State outputs.

QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS T_{amb} = 25°C; GND = 0V	TYPICAL	UNIT
t_{PLH} t_{PHL}	Propagation delay nAx to n$\overline{Y}$x	C_L = 50pF; V_{CC} = 5V	3.1	ns
C_{IN}	Input capacitance	V_I = 0V or V_{CC}	4	pF
C_{OUT}	Output capacitance	Outputs disabled; V_O = 0V or V_{CC}	7	pF
I_{CCZ}	Total supply current	Outputs disabled; V_{CC} =5.5V	50	µA

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
20-Pin Plastic DIP	–40°C to +85°C	74ABT240 N	74ABT240 N	SOT146-1
20-Pin plastic SO	–40°C to +85°C	74ABT240 D	74ABT240 D	SOT163-1
20-Pin Plastic SSOP Type II	–40°C to +85°C	74ABT240 DB	74ABT240 DB	SOT339-1
20-Pin Plastic TSSOP Type I	–40°C to +85°C	74ABT240 PW	74ABT240PW DH	SOT360-1

PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
2, 4, 6, 8	1A0 – 1A3	Data inputs
11, 13, 15, 17	2A0 – 2A3	Data inputs
18, 16, 14, 12	1$\overline{Y}$0 – 1$\overline{Y}$3	Data outputs
9, 7, 5, 3	2$\overline{Y}$0 – 2$\overline{Y}$3	Data outputs
1, 19	1$\overline{OE}$, 2$\overline{OE}$	Output enables
10	GND	Ground (0V)
20	V_{CC}	Positive supply voltage

PIN CONFIGURATION

1$\overline{OE}$	1	20	V_{CC}
1A0	2	19	2$\overline{OE}$
2$\overline{Y}$0	3	18	1$\overline{Y}$0
1A1	4	17	2A0
2$\overline{Y}$1	5	16	1$\overline{Y}$1
1A2	6	15	2A1
2$\overline{Y}$2	7	14	1$\overline{Y}$2
1A3	8	13	2A2
2$\overline{Y}$3	9	12	1$\overline{Y}$3
GND	10	11	2A3

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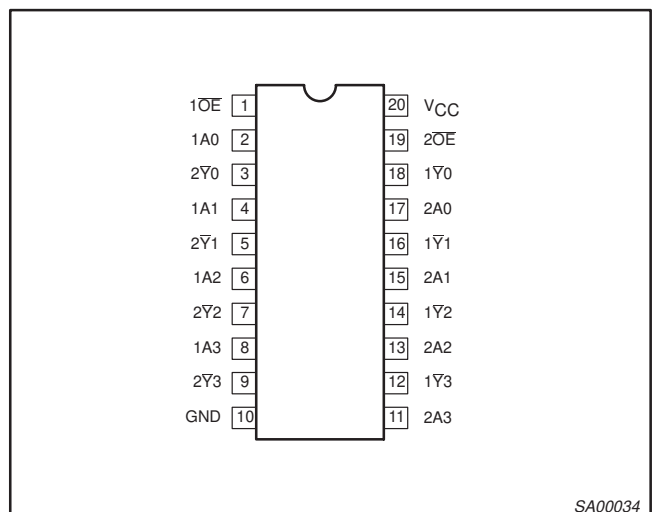
Octal inverting buffer (3-State)

74ABT240

LOGIC SYMBOL

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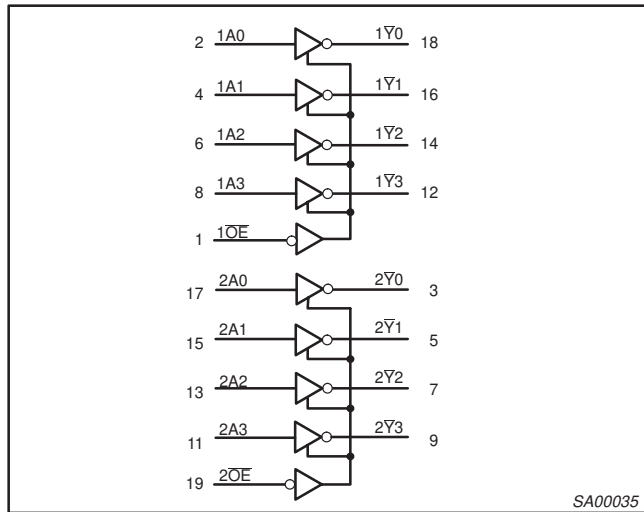
LOGIC SYMBOL (IEEE/IEC)

SA00036
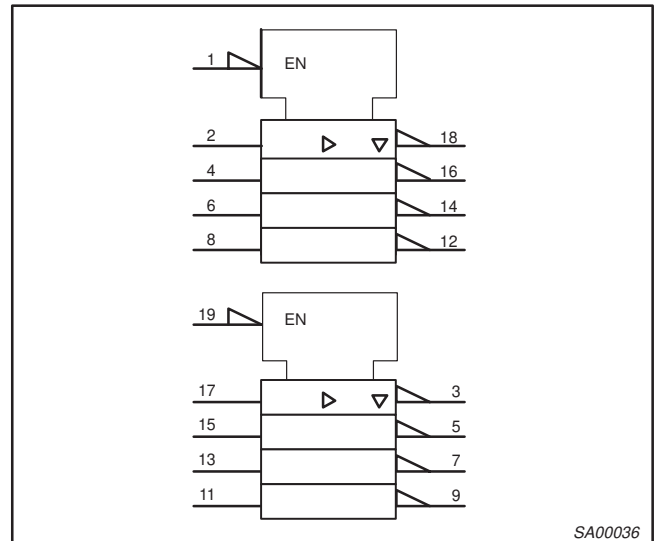
FUNCTION TABLE

INPUTS				OUTPUTS	
$1\overline{OE}$	1An	$2\overline{OE}$	2An	$1\overline{Y}n$	$2\overline{Y}n$
L	L	L	L	H	H
L	H	L	H	L	L
H	X	H	X	Z	Z

H = High voltage level
L = Low voltage level
X = Don't care
Z = High impedance "off" state

ABSOLUTE MAXIMUM RATINGS[1, 2]

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V_{CC}	DC supply voltage		−0.5 to +7.0	V
I_{IK}	DC input diode current	$V_I < 0$	−18	mA
V_I	DC input voltage[3]		−1.2 to +7.0	V
I_{OK}	DC output diode current	$V_O < 0$	−50	mA
V_{OUT}	DC output voltage[3]	output in Off or High state	−0.5 to +5.5	V
I_{OUT}	DC output current	output in Low state	128	mA
T_{stg}	Storage temperature range		−65 to 150	°C

NOTES:
1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
2. The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.
3. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

Octal inverting buffer (3-State)

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RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	LIMITS		UNIT
		Min	Max	
V_{CC}	DC supply voltage	4.5	5.5	V
V_I	Input voltage	0	V_{CC}	V
V_{IH}	High-level input voltage	2.0		V
V_{IL}	Low-level Input voltage		0.8	V
I_{OH}	High-level output current		−32	mA
I_{OL}	Low-level output current		64	mA
$\Delta t/\Delta v$	Input transition rise or fall rate	0	10	ns/V
T_{amb}	Operating free-air temperature range	−40	+85	°C

DC ELECTRICAL CHARACTERISTICS

SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS					UNIT
			T_{amb} = +25°C			T_{amb} = −40°C to +85°C		
			Min	Typ	Max	Min	Max	
V_{IK}	Input clamp voltage	V_{CC} = 4.5V; I_{IK} = −18mA		−0.9	−1.2		−1.2	V
V_{OH}	High-level output voltage	V_{CC} = 4.5V; I_{OH} = −3mA; V_I = V_{IL} or V_{IH}	2.5	2.9		2.5		V
		V_{CC} = 5.0V; I_{OH} = −3mA; V_I = V_{IL} or V_{IH}	3.0	3.4		3.0		V
		V_{CC} = 4.5V; I_{OH} = −32mA; V_I = V_{IL} or V_{IH}	2.0	2.4		2.0		V
V_{OL}	Low-level output voltage	V_{CC} = 4.5V; I_{OL} = 64mA; V_I = V_{IL} or V_{IH}		0.42	0.55		0.55	V
I_I	Input leakage current	V_{CC} = 5.5V; V_I = GND or 5.5V		±0.01	±1.0		±1.0	μA
I_{OFF}	Power-off leakage current	V_{CC} = 0.0V; V_I or V_O ≤ 4.5V;		±5.0	±100		±100	μA
I_{PU}/I_{PD}	Power-up/down 3-state output current[3]	V_{CC} = 2.1V; V_O = 0.5V; V_I = GND or V_{CC}; V_{OE} = Don't care		±5.0	±50		±50	μA
I_{OZH}	3-State output High current	V_{CC} = 5.5V; V_O = 2.7V; V_I = V_{IL} or V_{IH}		5.0	50		50	μA
I_{OZL}	3-State output Low current	V_{CC} = 5.5V; V_O = 0.5V; V_I = V_{IL} or V_{IH}		−5.0	−50		−50	μA
I_{CEX}	Output High leakage current	V_{CC} = 5.5V; V_O = 5.5V; V_I = GND or V_{CC}		5.0	50		50	μA
I_O	Output current[1]	V_{CC} = 5.5V; V_O = 2.5V	−50	−100	−180	−50	−180	mA
I_{CCH}		V_{CC} = 5.5V; Outputs High, V_I = GND or V_{CC}		50	250		250	μA
I_{CCL}	Quiescent supply current	V_{CC} = 5.5V; Outputs Low, V_I = GND or V_{CC}		24	30		30	mA
I_{CCZ}		V_{CC} = 5.5V; Outputs 3-State; V_I = GND or V_{CC}		50	250		250	μA
ΔI_{CC}	Additional supply current per input pin[2]	Outputs 3-State, one input at 3.4V, other inputs at V_{CC} or GND; V_{CC} = 5.5V		0.5	1.5		1.5	mA

NOTES:
1. Not more than one output should be tested at a time, and the duration of the test should not exceed one second.
2. This is the increase in supply current for each input at 3.4V.
3. This parameter is valid for any V_{CC} between 0V and 2.1V, with a transition time of up to 10msec. From V_{CC} = 2.1V to V_{CC} 5V ± 10% a transition time of up to 100μsec is permitted.
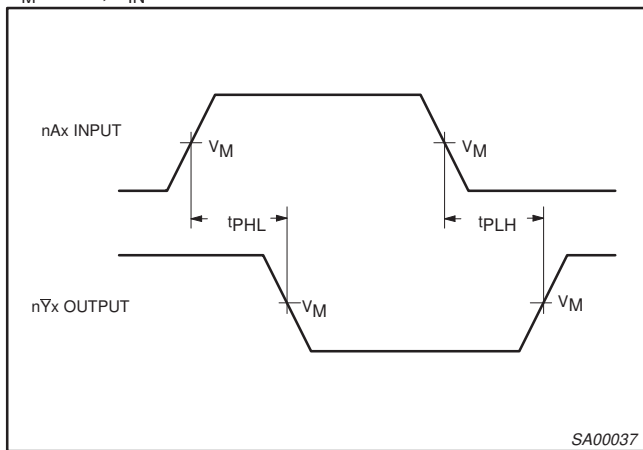
Octal inverting buffer (3-State)

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AC CHARACTERISTICS

GND = 0V; t_R = t_F = 2.5ns; C_L = 50pF, R_L = 500Ω

SYMBOL	PARAMETER	WAVEFORM	LIMITS					UNIT
			T_{amb} = +25°C V_{CC} = +5.0V			T_{amb} = −40°C to +85°C V_{CC} = +5.0V ±0.5V		
			Min	Typ	Max	Min	Max	
t_{PLH} t_{PHL}	Propagation delay nAx to n$\overline{Y}$x	1	1.0 1.6	2.7 3.5	4.1 4.3	1.0 1.6	4.8 4.8	ns
t_{PZH} t_{PZL}	Output enable time to High and Low level	2	1.1 1.1	3.1 4.2	4.7 5.8	1.1 1.1	5.2 6.2	ns
t_{PHZ} t_{PLZ}	Output disable time from High and Low level	2	1.8 1.6	3.7 3.0	5.7 5.4	1.8 1.6	6.4 5.8	ns

AC WAVEFORMS

V_M = 1.5V, V_{IN} = GND to 3.0V

SA00037

Waveform 1. Waveforms Showing the Input (nAx) to Output (n$\overline{Y}$x) Propagation Delays

SA00017
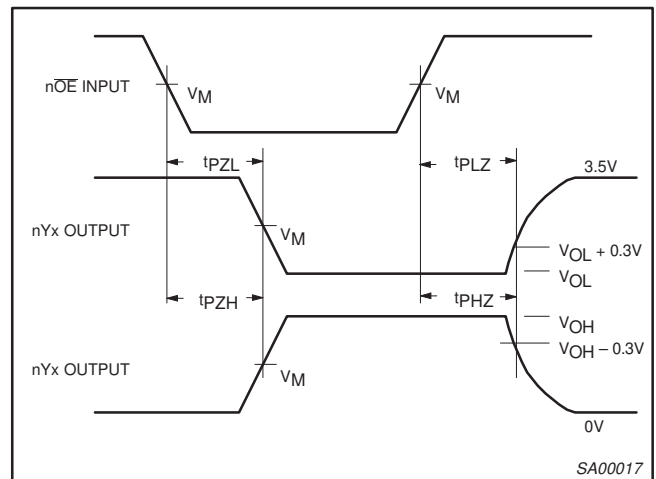
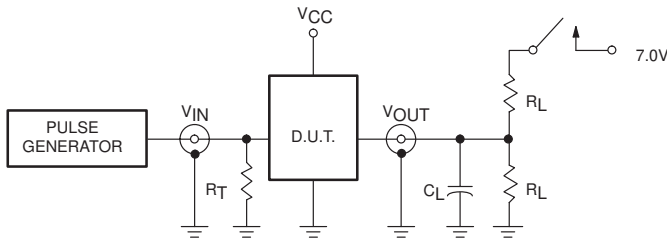**Waveform 2. Waveforms Showing the 3-State Output Enable and Disable Times**
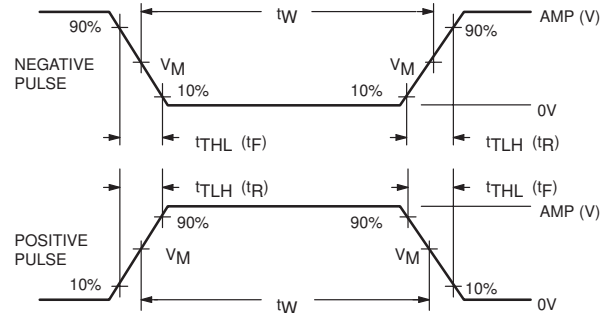
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TEST CIRCUIT AND WAVEFORMS

Test Circuit for 3-State Outputs

Input Pulse Definition

$V_M = 1.5V$

SWITCH POSITION

TEST	SWITCH
t_{PLZ}	closed
t_{PZL}	closed
All other	open

DEFINITIONS

R_L = Load resistor; see AC CHARACTERISTICS for value.

C_L = Load capacitance includes jig and probe capacitance; see AC CHARACTERISTICS for value.

R_T = Termination resistance should be equal to Z_{OUT} of pulse generators.

FAMILY	INPUT PULSE REQUIREMENTS				
	Amplitude	Rep. Rate	t_W	t_R	t_F
74ABT	3.0V	1MHz	500ns	2.5ns	2.5ns

SA00012